

Supporting information

Enhanced oxide ion conductivity in sodium niobate-based ceramics

Pengrong Ren^{1,*}, Luting Lu¹, Ming Li², Xin Wang³

¹ Shaanxi Province Key Laboratory for Electrical Materials and Infiltration

Technology, School of Materials Science and Engineering, Xi'an University of

Technology, Xi'an 710048, China

² Advanced Materials Research Group, Department of Mechanical, Materials and

Manufacturing Engineering, Faculty of Engineering, University of Nottingham,

Nottingham NG7 2RD, UK

³ Laboratory of Thin Film Techniques and Optical Test, School of Photoelectrical

Engineering, Xi'an Technological University, Xi'an 710032, China

* Corresponding author, renpengrongxaut@126.com (P. Ren)

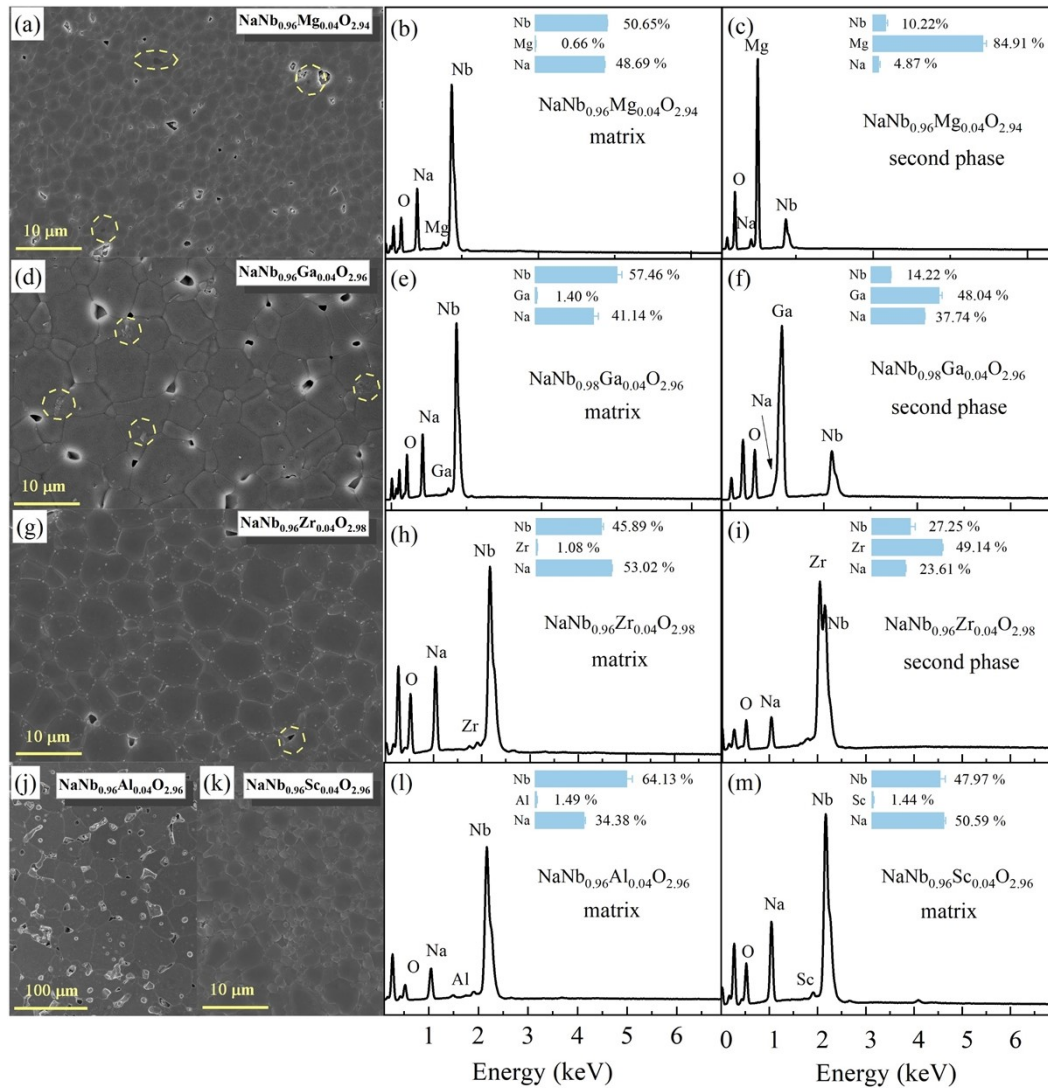


Fig. S1. SEM images and EDS spectra of $\text{NaNb}_{0.96}\text{Mg}_{0.04}\text{O}_{2.94}$, $\text{NaNb}_{0.96}\text{Al}_{0.04}\text{O}_{2.96}$, $\text{NaNb}_{0.96}\text{Ga}_{0.04}\text{O}_{2.96}$, $\text{NaNb}_{0.96}\text{Sc}_{0.04}\text{O}_{2.96}$ and $\text{NaNb}_{0.96}\text{Zr}_{0.04}\text{O}_{2.98}$ ceramics. secondary phase marked with yellow dashed circle.

Table. S1. Relative density of $\text{NaNb}_{0.96}\text{Mg}_{0.04}\text{O}_{2.94}$, $\text{NaNb}_{0.96}\text{Al}_{0.04}\text{O}_{2.96}$, $\text{NaNb}_{0.96}\text{Ga}_{0.04}\text{O}_{2.96}$, $\text{NaNb}_{0.96}\text{Sc}_{0.04}\text{O}_{2.96}$ and $\text{NaNb}_{0.96}\text{Zr}_{0.04}\text{O}_{2.98}$ ceramics. The optimum sintering temperatures are highlighted in color.

Samples	Sintering temperature (°C)	Density (g/cm ³)
$\text{NaNb}_{0.96}\text{Mg}_{0.04}\text{O}_{2.94}$	1025	4.4099
	1050	4.4299
	1075	4.3911

	1275	4.2535
NaNb _{0.96} Al _{0.04} O _{2.96}	1300	4.2832
	1325	4.2020
	1100	4.2681
NaNb _{0.96} Ga _{0.04} O _{2.96}	1125	4.3770
	1150	4.3256
	1175	4.3533
NaNb _{0.96} Sc _{0.04} O _{2.96}	1200	4.4133
	1225	4.3821
	1275	4.4142
NaNb _{0.96} Zr _{0.04} O _{2.98}	1300	4.4232
	1325	4.3943

Fig. S2 shows XRD patterns of NaNb_{1-x}Mg_xO_{3-3x/2}, NaNb_{1-y}Ga_yO_{3-y} ceramics. No secondary phases are detected for all specimens at the detection threshold of the XRD instrument. Fig. S3 shows the typical microstructural morphologies of NaNb_{1-x}Mg_xO_{3-3x/2}, NaNb_{1-y}Ga_yO_{3-y} ceramics. As shown in the table S1, the relative density of all samples decreases with increasing Mg²⁺ and Ga³⁺ doping content. Although XRD displays the presence of a pure perovskite structure, the microstructure of the NaNb_{1-x}Mg_xO_{3-3x/2} samples also indicate a small number of secondary phases (marked with yellow dashed circles). A small amount of the secondary phases is also presented in the NaNb_{1-y}Ga_yO_{3-y} specimen, indicating that MgO and Ga₂O₃ are not completely dissolved into the NN lattice. As shown in Fig. S3, there are small changes in average grain size

of $\text{NaNb}_{1-x}\text{Mg}_x\text{O}_{3-3x/2}$. The average grain size decreases and then increases with increasing x , from $2.96\ \mu\text{m}$ for $x = 0.02$ to $2.52\ \mu\text{m}$ for $x = 0.04$ and then to $3.09\ \mu\text{m}$ for $x = 0.06$. The average grain size of $\text{NaNb}_{1-y}\text{Ga}_y\text{O}_{3-y}$ decreases with increasing y , from $4.69\ \mu\text{m}$ for $y = 0.02$, to $4.41\ \mu\text{m}$ for $y = 0.04$, and $4.06\ \mu\text{m}$ for $y = 0.06$. The presence of the secondary phase inhibits the migration of grain boundaries, which leads to a decrease in grain size.

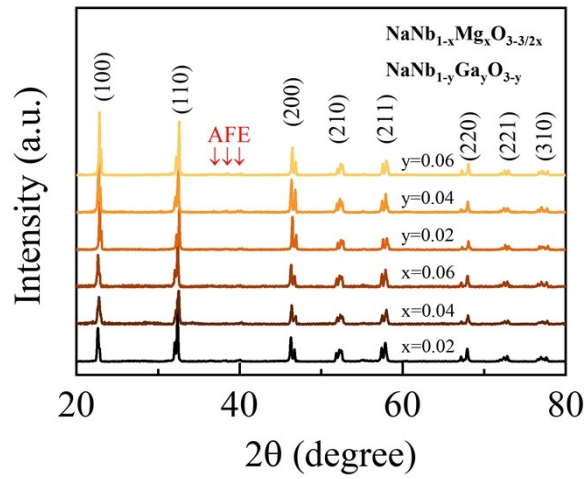


Fig. S2. XRD patterns of $\text{NaNb}_{1-x}\text{Mg}_x\text{O}_{3-3x/2}$ and $\text{NaNb}_{1-y}\text{Ga}_y\text{O}_{3-y}$.

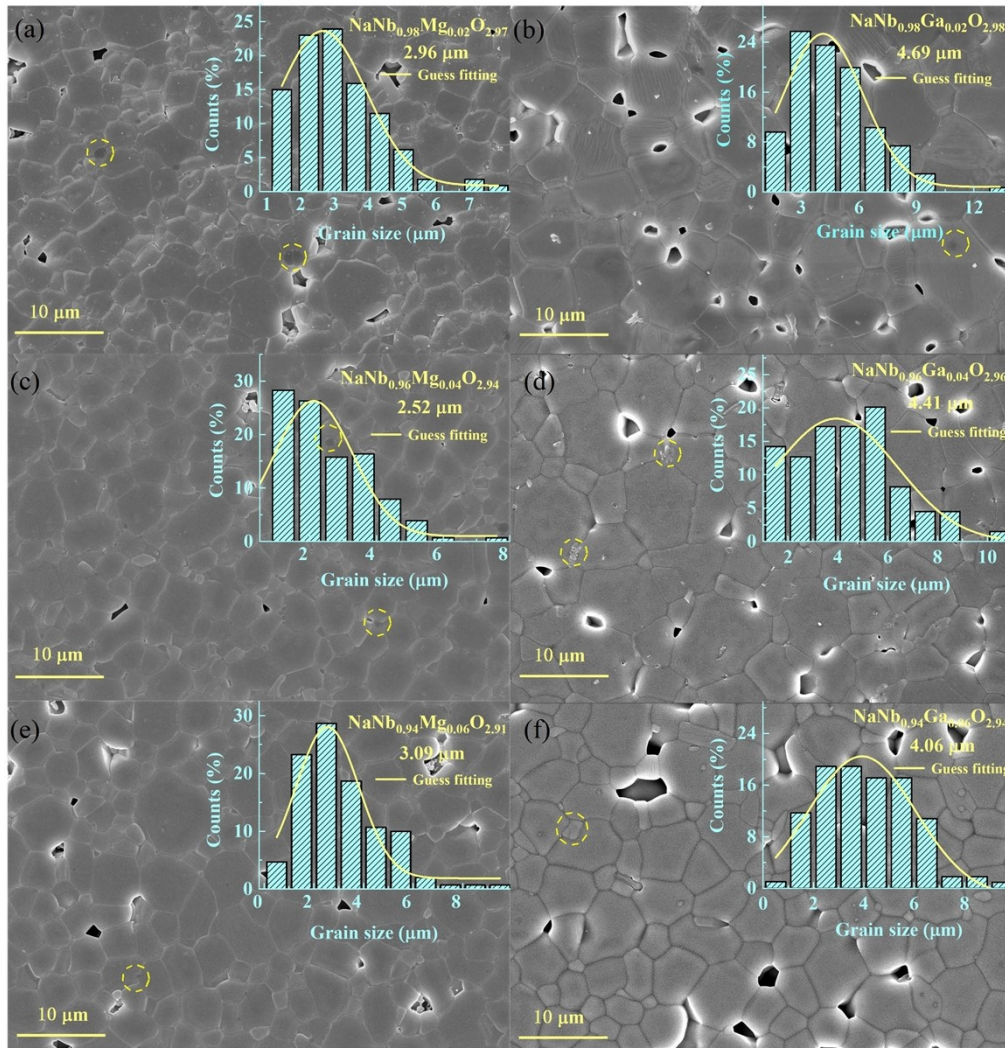


Fig. S3. SEM images of (a, c, e) $\text{NaNb}_{1-x}\text{Mg}_x\text{O}_{3-3x/2}$ and (b, d, f) $\text{NaNb}_{1-y}\text{Ga}_y\text{O}_{3-y}$ ceramics.

Table. S2. Relative density of $\text{NaNb}_{1-x}\text{Mg}_x\text{O}_{3-3x/2}$ and $\text{NaNb}_{1-y}\text{Ga}_y\text{O}_{3-y}$ ceramics.

Samples	x = 0.02	x = 0.04	x = 0.06	y = 0.02	y = 0.04	y = 0.06
Relative density	97.42%	97.20%	96.93%	96.69%	96.51%	96.33%

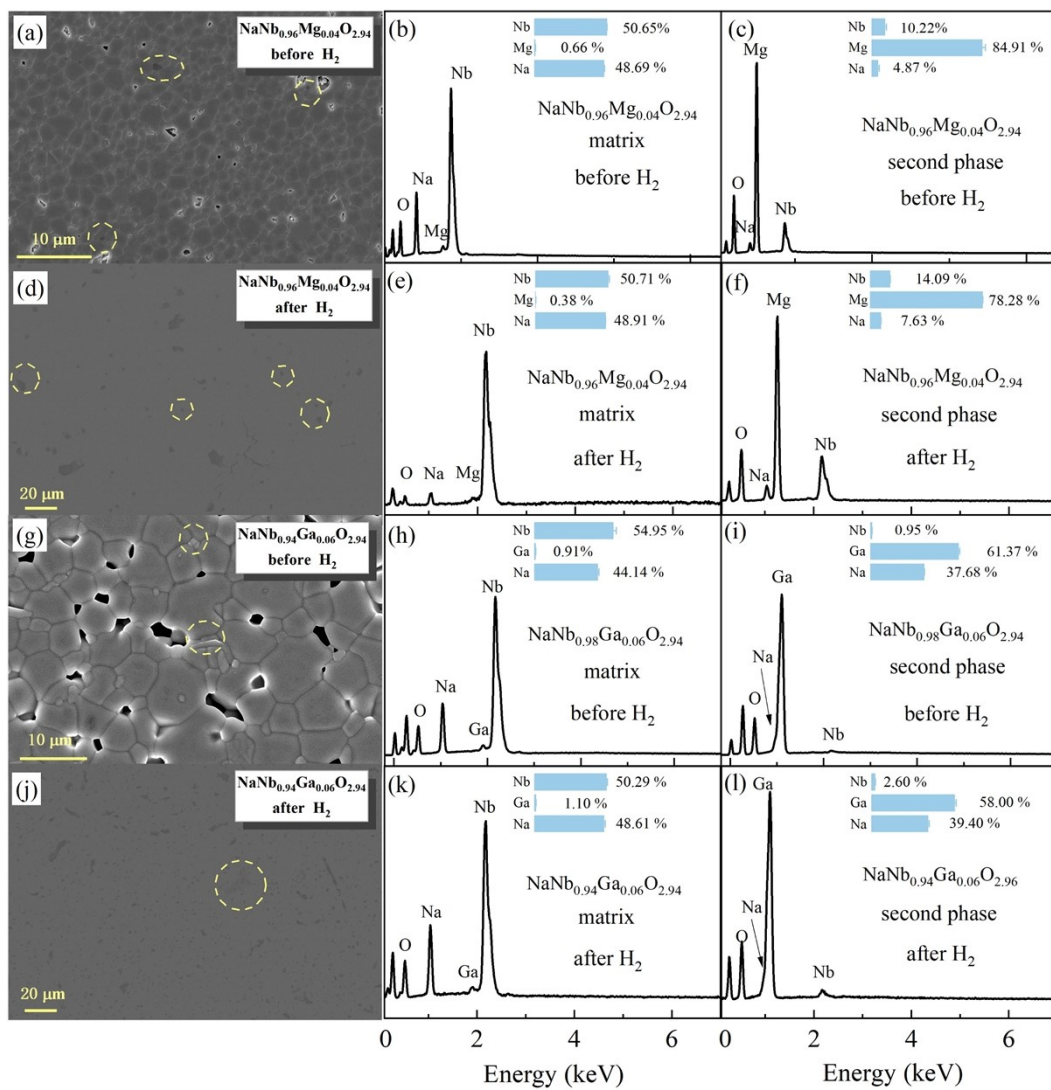


Fig. S4. SEM images and EDS spectra of $\text{NaNb}_{0.96}\text{Mg}_{0.04}\text{O}_{2.94}$ and $\text{NaNb}_{0.94}\text{Ga}_{0.06}\text{O}_{2.94}$ before and after annealed at 600 °C for 6 h in H_2 . The secondary phase is marked with yellow dashed circle.